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Angaben zur Veröffentlichung / Publication details:

Häusler, Wolfgang, and A. H. MacDonald. 2003. "Tunneling exponents in realistic quantum wires using the mean field approximation." *Journal of the Physical Society of Japan* 72 (Suppl. A): 195–96. <https://doi.org/10.1143/jpsjs.72sa.195>.

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Tunneling exponents in realistic quantum wires using the mean field approximation

Wolfgang HÄUSLER^{1,*} and A.H. MACDONALD²

¹ *Physikalisches Institut, Universität Freiburg, Hermann-Herder-Str. 3, D-79104 Freiburg, Germany*

² *Department of Physics, University of Texas at Austin, Austin TX, 78712, U.S.A.*

Interacting carriers in one dimension (1D) are non-Fermi liquids with power laws for many correlations functions such as the tunneling density of states. Evidence for this behavior has been found in carbon nanotubes¹⁾ and, somewhat less convincingly, in semiconducting quantum wires²⁾ in the form of non-trivial temperature and transport voltage dependences. Non-universal exponents are expressed through one parameter K_ρ within the Tomonaga-Luttinger (TL) liquid theory.

In Fermi-liquids K_ρ equals unity. This quantity is commonly expected to decrease with increasing repulsion V_0 between the carriers, according to

$$K_\rho = [1 + 2V_0/\pi v_F]^{-1/2}. \quad (1)$$

Eq. (1) results also from the RPA-approximation for the 1D-plasmon velocity³⁾ which has shown to be exact for spinless carriers and for strictly linear kinetic energy dispersion.⁴⁾ Eq. (1) implies that $K_\rho \rightarrow 0$ with decreasing carrier density $n = 2k_F/\pi = 2mv_F/\pi$ for quadratic kinetic energy dispersion $\sim k^2/2m$ when $v_F = k_F/m$.⁵⁾

For given microscopic interaction potential $V(x)$, where the Coulomb form in any realistic sample layout will be screened by the nearest metals at a distance R , does K_ρ depend on the carrier density in a non-monotonous fashion, passing through a minimum before reaching the asymptotic value which was conjectured to be $K_\rho(n \rightarrow 0) \rightarrow 1/2$.⁶⁾ Observing this minimum could give direct experimental access to the range of the microscopic interaction. We shall argue that the value of K_ρ can be obtained quite accurately by the Hartree-Fock approximation when augmenting selfconsistency (SCHF).

As a realistic form modeling the microscopic interaction in a quantum wire of width d at particle separation $|x - x'|$ we use

$$V(|x|) = \frac{e^2}{\epsilon} \left(\frac{1}{\sqrt{x^2 + d^2}} - \frac{1}{\sqrt{x^2 + d^2 + 4R^2}} \right) \quad (2)$$

with $V(|x - x'| \gg R) \sim |x - x'|^{-3}$, describing dipolar screening. We have solved the Hartree-Fock equations for a system of length L , accounting for the quadratic kinetic energy dispersion and for spin $s = \pm$

$$0 = \left[\frac{1}{2} \left(2j - \frac{k}{k_F} \right)^2 - \frac{\varepsilon_{ks}}{k_F v_F} \right] u_{j,k,s} \quad (3)$$

$$+ \frac{L}{2k_F \pi} \sum_{j'j''} u_{j'',k,s} \int_{-k_F}^{k_F} dk' \left\{ \hat{V}(2(j - j'')) \times \sum_{s'} u_{-j+j'+j'',k',s'}^* u_{j',k',s'} - \hat{V} \left(2(j - j') - \frac{k}{k_F} + \frac{k'}{k_F} \right) u_{-j+j'+j'',k',s}^* u_{j',k',s} \right\}$$

selfconsistently in k -space for the coefficients $u_{j,k,s}$ ($-k_F \leq k \leq k_F$) that expand the HF-orbitals (index j) as Bloch waves

$$\psi_{ks}(x) = e^{ikx} \sum_j u_{j,k,s} e^{ij2k_F x}. \quad (4)$$

Resulting total ground state energy densities E_0^{HF}/L are differentiated twice w.r.t. n to obtain the HF-estimate to the compressibility $\kappa = [\partial^2(E_0/L)/\partial n^2]^{-1}$. Using the exact thermodynamic relationship

$$K_\rho = \sqrt{\pi v_F \kappa / 2} \quad (5)$$

from TL-theory⁷⁾ yields $1/K_\rho^{\text{HF}}$, shown in Fig. 1. Also included in Fig. 1 are quantum Monte Carlo data taken from Ref.⁸⁾ that, within symbol size, can be regarded as exact. It is seen that K_ρ^{HF} does reproduce all of the available QMC-data points amazingly well. In view of the pronounced correlations of interacting one-dimensional Fermions, which prohibit for example to express the ground state wave function analytically, such a quite satisfying mean-field approach might seem unexpected.

The following general trends are seen in Fig. 1:

(i) The high density region $k_F d \gtrsim 0.25$, corresponding to $r_s \lesssim 1.6$, may be regarded as the perturbational or RPA regime. Here Eq. (1) may be improved slightly by accounting for the exchange contribution $\sim -\hat{V}(2k_F)$. Despite of the quite small values of K_ρ estimated⁹⁾ and observed¹⁾ in carbon they nanotubes belong typically to this regime, since mean carrier separations exceed by far the interaction range (which can reach the order of the tube length).

(ii) Between $0.1 \lesssim k_F d \lesssim 0.25$ the perturbational expression still allows to guess K_ρ . Here, particularly the SCHF but also the QMC-data indicate slightly enhanced K_ρ^{-1} -values, relative to Eq. (1). By virtue of (5) this suggests a *reduced* compressibility which can be interpreted as precursor to a Wigner crystal phase transition (that cannot be completed in 1D). There, K_ρ has been esti-

* haeusler@physnet.uni-hamburg.de

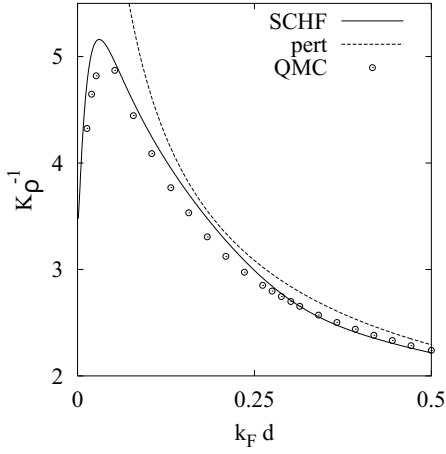


Fig. 1. K_ρ^{-1} versus carrier density. The units can be translated into the r_s -Fermi liquid parameter using $r_s = \pi/8k_F d$. The range of the microscopic interaction (2) is $R/d = 14.1$. Solid: self consistent HF approximation, dashed: Eq. (1). QMC-data are taken from Ref.⁸⁾

mated first in.¹⁰⁾

(iii) Finally, for the interaction range $R/d = 14.1$ shown in Fig. 1, a maximum is seen below $k_F d \lesssim 0.1$ ($r_s \gtrsim 4$) in both, the SCHF and the QMC results, in qualitative difference to the monotonous increase of the perturbative expression (1). This maximum occurs roughly when $k_F R \approx \pi/8$ (R has to be significantly smaller than the mean carrier spacing due to quantum fluctuations). In semiconducting quantum wires this regime (iii) should be feasible.

It has been conjectured that $1/K_\rho$ would approach 2

when $k_F \rightarrow 0$.⁶⁾ This limit is not confirmed by the SCHF which, when carried out carefully to account for the pronounced $4k_F$ -periodic oscillations of the SCHF-density (resembling a Wigner crystal), yields $1/K_\rho^{\text{HF}} \rightarrow 3.3$ with a weak dependence on R/d , ranging from $1/K_\rho^{\text{HF}} \rightarrow 3.0$ at $R/d = 5.7$ to $1/K_\rho^{\text{HF}} \rightarrow 3.5$ at $R/d = 35$. Unfortunately, the QMC-data cannot discriminate between $1/K_\rho \rightarrow 2$ and $1/K_\rho \rightarrow 3.5$. This discrepancy might indicate the failure of the mean field approximation to estimate K_ρ in the strongly correlated regime of very small carrier densities.

We would like to acknowledge useful discussions with Charles Creffield and with Hermann Grabert.

- 1) M. Bockrath, *et al.*, Nature **397** (1999) 598.
- 2) S. Tarucha, T. Honda, and T. Saku, Solid State Comm. **94** (1995) 413; A. Yacoby, *et al.*, Phys. Rev. Lett. **77** (1996) 4612; O.M. Auslaender, *et al.*, Phys. Rev. Lett. **84** (2000) 1764; M. Rother, *et al.*, Physica E **6** (2000) 551.
- 3) Q.P. Li, S. Das Sarma, and R. Joynt, Phys. Rev. B **45** (1992) 13713.
- 4) I.E. Dzyaloshinskii and A.I. Larkin, Sov. Phys. JETP, **38** (1974) 202.
- 5) In systems with strict linear dispersion, such as carbon nanotubes, the value of the K_ρ -parameter cannot be regulated by varying the carrier density. This case is not investigated here.
- 6) W. Häusler, L. Kecke, and A.H. MacDonald, Phys. Rev. B **65** (2002) 085104.
- 7) F.D.M. Haldane, J. Phys. C **14** (1981) 2585.
- 8) C.E. Creffield, W. Häusler, and A.H. MacDonald, Europhys. Lett. **53** (2001) 221.
- 9) R. Egger and A.O. Gogolin, Eur. Phys. J. B **3** (1998) 281.
- 10) L. I. Glazman, I. M. Ruzin, and B. I. Shklovskii, Phys. Rev. B **45** (1992) 8454.